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SEMICONDUCTOR®

FSHDMI04 Wide-bandwidth Differential Signaling HDMI Switch (Preliminary)

General Description

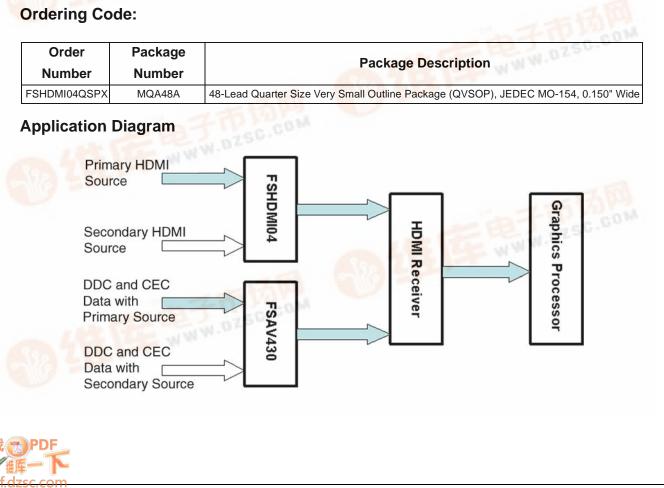
The FSHDMI04 is a wide bandwidth switch for routing HDMI Link Data and Clock signals. This device supports data rates up to 1.65Gbps per channel for UXGA resolution. It can also be used to switch other LVDS or TMDS based DVI digital video signals as well as 1000-BaseT Gigabit Ethernet. Possible applications include LCD TV, DVD, Set-Top Box, and notebook computer and other designs with multiple digital video interfaces. The FSHDMI04 switch allows the passage of HDMI link signals with low non-adjacent channel crosstalk and superior OFF-Isolation. This performance is critical to minimize ghost images between active video sources in video applications. The wide bandwidth of this switch allows the high speed differential signal to pass through the switch with minimal additive skew and phase jitter.

Features

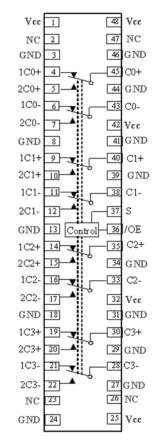
- 1.65 Gbps Throughput
- -25dB non-adjacent channel crosstalk at 825MHz
- Isolation ground between channels
- Fast turn on/off time
- Low power consumption (1µA max)
- Control input: TTL compatible
- Available in 48-lead QVSOP package

Applications

■ UXGA and 1080p DVI and HDMI video source selection



Pin Assignments



Truth Table

S	OE	Function
Х	Н	Disconnected
L	L	$1C_n = C_n$
Н	L	$2 C_n = C_n$

Pin Descriptions

Pin Name	Description		
OE	Bus Switch Enable		
S	Select Input		
1C _n , 2C _n , C0 _n , C1 _n , C2 _n , C3 _n	Data Ports		

Absolute Maximum Ratings(Note 1)

Supple Voltage (V _{CC})	-0.5V to +4.6V
DC Switch Voltage (V _S)	–0.5V to V_CC +0.05
DC Input Voltage (VIN) (Note 2)	-0.5V to +4.6V
DC Input Diode Current (I _{IK})	–50 mA
DC Output (I _{OUT}) Sink Current	128 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
ESD	
Human Body Model	4kV

Recommended Operating Conditions (Note 3)

Power Supply Operating (V_{CC})	3.0V to 3.6V
Control Input Voltage (V _{IN})	0V to V_{CC}
Switch Input Voltage	0V to V_{CC}
Operating Temperature	–40°C to 85°C

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The Recommended Operating Conditions tables will defined the conditions for actual device operation.

Note 2: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 3: Unused control inputs must be held HIGH or LOW. They may not float

DC Electrical Characteristics (All typical values are for V_{CC} = 3.3V @ 25°C unless otherwise specified)

		V _{CC} (V)	T _A = -40°C to +85°C				
Symbol	Parameter		Min	Typ (Note 4)	Max	Units	Conditions
V _{IK}	Clamp Diode Voltage	3.0			-1.2	V	$I_{IN} = -18mA$
VIH	Input Voltage HIGH	3.0 - 3.6	2.0			V	
VIL	Input Voltage LOW	3.0 - 3.6			0.8	V	
I _{IN}	Control Input Leakage	3.6			±1.0	μA	$V_{IN} = 0$ to V_{CC}
I _{OZ}	OFF-STATE Leakage	3.6			±1.0	μA	$0 \leq nC_n, \ C_n \leq V_{CC}$
R _{ON}	Switch On Resistance (Note 4)	3.0			15.0	Ω	$V_{\text{IN}} = V_{\text{CC}} - 0.6$ to $V_{\text{CC}}, I_{\text{ON}} = 10 \text{mA}$
R _{ON(FLAT)}	Switch On Resistance Flatness (Note 4)	3.0			2.0	Ω	$V_{\text{IN}} = V_{\text{CC}} - 0.6$ to $V_{\text{CC}}, I_{\text{ON}} = 10 \text{mA}$
I _{CC}	Quiescent Supply Current (Note 5)	3.6			1.0	μA	$V_{IN} = 0$ or V_{CC} , $I_{OUT} = 0$
ICCT	Increase in I _{CC} Current per Control Voltage (Note 5)	3.6			50.0	μΑ	One Input at 3.0V, Others at 0V or $\rm V_{CC}$

Note 4: Measured by the voltage drop between A and B pins at the indicated current through the switch. On Resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 5: This specification applies to pass gate architecture only.

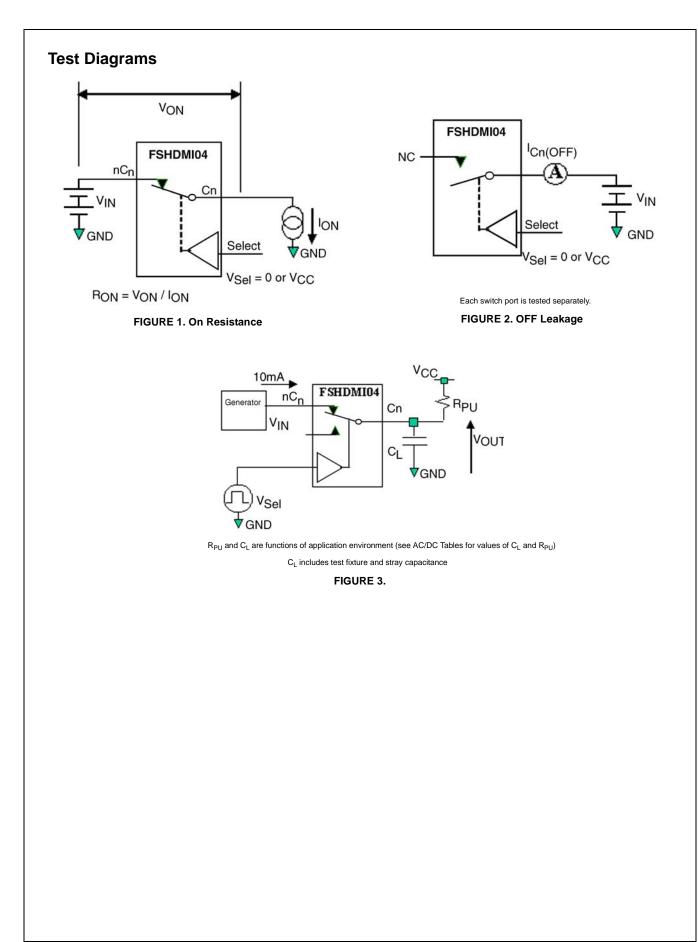
AC Electrical Characteristics (All typical values are for 25°C unless otherwise specified)

Symbol		V _{CC} (V)	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$					-	
	Parameter		Min	Typ (Note 6)	Max	Units	Conditions	Figure Number	
t _{ON}	Turn ON Time S-to-Output	3.0 to 3.6		4.8	6.0	ns	$V_{\text{IN}} = V_{\text{CC}} - 0.5, \text{ R}_{\text{PU}} = 50\Omega, \text{ C}_{\text{L}} = 5\text{pF}$	Figures 3, 4	
toff	Turn OFF Time S-to-Output	3.0 to 3.6		2.2	4.0	ns	$V_{\text{IN}} = V_{\text{CC}} - 0.5, \text{ R}_{\text{PU}} = 50\Omega, \text{ C}_{\text{L}} = 5\text{pF}$	Figures 3, 4	
t _{BBM}	Break-Before-Make Time	3.0 to 3.6	1.0				$V_{IN} = V_{CC} - 0.5, R_{PU} = 20\Omega, C_L = 5pF$	Figure 10	
$t_{PD}~(t_{PLH},~t_{PHL})$	Switch Propagation Delay (Note 6)	3.0 to 3.6			250	ps	$R_{PU} = 50\Omega, C_L = 5pF$	Figures 3, 9	
T _{JITTER}	Total Jitter (DJ + RJ)	0.04-0.0			90.0	ps	f = 165MHz Clock with 50% Duty Cycle,	Einer O	
T _{RATIO}	Duty Cycle Ratio	3.0 to 3.6	40.0	50.0	60.0	%	RPU = 50Ω, CL = 5pF	Figure 3	
T _{SK1}	Intra-Pair Skew	0.045.0.0			90.0		f = 740Mbps, 2 ²³ -1 PRBS R _{PU} = 50Ω, C _L = 5pF	Figures 3, 9	
	C_{n^+} to C_{n^-}	3.0 to 3.6			70.0	ps	f = 1.65Gbps, 2^{23} -1 PRBS R _{PU} = 50Ω, C _L = 5pF		
T _{SK2}	Inter-Pair Skew				250		f = 740Mbps, 2 ²³ -1 PRBS $R_{PU} = 50\Omega$, $C_L = 5pF$	Figures 3, 9	
	(Between any two switch paths)	3.0 to 3.6			250	ps	f = 1.65Gbps, 2^{23} -1 PRBS R _{PU} = 50 Ω , C _L = 5pF		
O _{IRR}	OFF-Isolation	3.0 to 3.6		-55.0			$R_T = 50\Omega$, f = 10MHz		
		3.0 to 3.6		-32.0		dB	$R_T = 50\Omega$, f = 165MHz	Figure 5	
		3.0 to 3.6		-30.0		uв	$R_T = 50\Omega$, f = 370MHz		
		3.0 to 3.6	-25.0	-27.0			$R_T = 50\Omega$, f = 825MHz		
Xtalk N	Non-Adjacent Channel Crosstalk	3.0 to 3.6		-75.0			$R_T = 50\Omega$, f = 10MHz	Figure 6	
		3.0 to 3.6		-40.0		dB	$R_T = 50\Omega$, f = 165MHz		
		3.0 to 3.6		-30.0		uв	R _T = 50Ω, f = 370MHz		
		3.0 to 3.6	-25.0	-27.0			R _T = 50Ω, f = 825MHz		
f _{MAX}	Maximum Throughput	3.3		1.65		Gbps			
BW	Bandwidth (Note 6)	3.3		825		MHz	$R_{T} = 50\Omega, C_{L} = 5pF$		

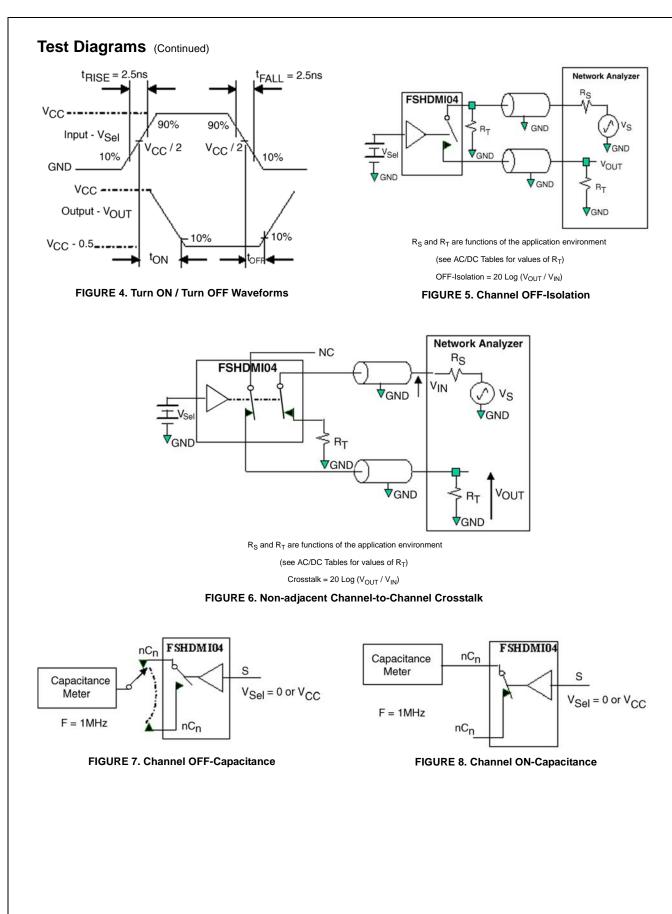
Note 6: This specification applies to pass gate architecture ONLY. For active switch design, it allows up to 60mA power consumption. Propagation delay for active architecture design is allowed to be 1ns. 150ps specification applies to pass gate design ONLY. This specification is also not production tested.

Capacitance

Symbol	Parameter		T _A = -40°C to +85°C	c	Units	Conditions	
Symbol	Falameter	Min	Тур	Max	Units	Conditions	
C _{IN}	Control Pin Input Capacitance		1.5		pF	$V_{CC} = 0V$	
C _{ON}	nC _n ON Capacitance		6.0		pF	V _{CC} = 3.3V	
C _{OFF}	Port C _n OFF Capacitance		4.5		pF	V _{CC} = 3.3V	



FSHDMI04



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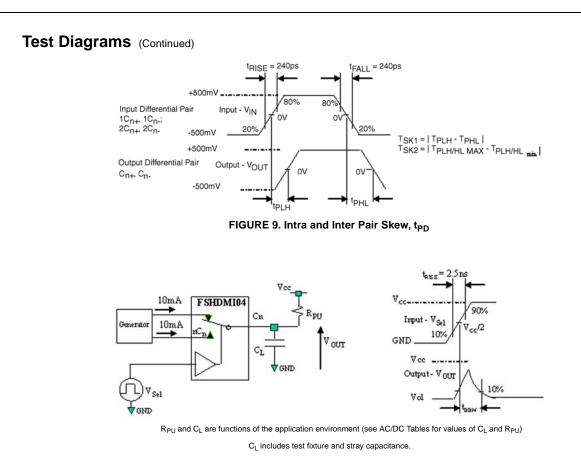
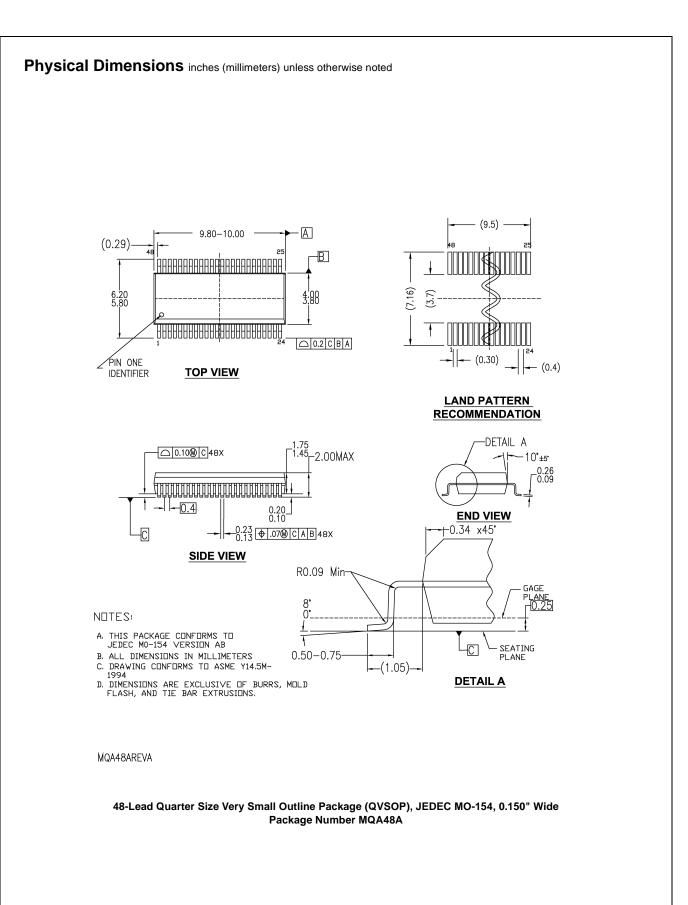


FIGURE 10. Break-Before-Make

FSHDMI04





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Datasheet Identification	Product Status	Definition			
Datasheet lacintinoation	i roduot otatus	Deminion			
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